

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1157	257/314.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/27 13:57
L2	2121	257/315.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/27 14:13
L3	2042	257/316.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/27 14:25
L4	3	((semiconductor with nonvolatile with memory) and ((active adj region) with parallel) and (isolation with linearly) and (gate with orthogonally) and (floating adj gate) and (control adj gate) and (conductor with metal) and contact).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/27 14:29
L5	3	4 and (second with metal).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/27 14:30
S1	4189	(nonvolatile with memory) and (gate with floating) and (gate with control)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 10:42
S2	1501	((nonvolatile with memory) and (gate with floating) and (gate with control)) and source and drain and parallel	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 10:19
S3	1242	((nonvolatile with memory) and (gate with floating) and (gate with control)) and source and drain and parallel) and (memory).ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 10:20
S4	11	((nonvolatile with memory) and (gate with floating) and (gate with control)) and source and drain and parallel) and (memory).ab.) and ((conductor or wir\$3) with copper)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 11:17
S5	8	("4775642"   "4808261"   "4997777"   "5658813"   "5789294"   "5846861"   "5976934"   "6083791").PN.	USPAT	OR	ON	2003/04/04 10:28

S6	524	(((((nonvolatile with memory) and (gate with floating) and (gate with control)) and source and drain and parallel) and (memory).ab.) and nonvolatile.ab.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 11:18
S7	16	(((((nonvolatile with memory) and (gate with floating) and (gate with control)) and source and drain and parallel) and (memory).ab.) and nonvolatile.ab.) and (element adj isolation adj region)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 12:25
S8	3	("5293331"   "5657271"   "5828602").PN.	USPAT	OR	ON	2003/04/04 11:48
S9	510	257/314.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/27 13:50
S10	1118	257/315.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 13:42
S11	1481	257/316.ccls.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 14:00
S12	150	(((((nonvolatile with memory) and (gate with floating) and (gate with control)) and source and drain and parallel) and (memory).ab.) and (isolation adj region)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 14:01
S13	53	(((((nonvolatile with memory) and (gate with floating) and (gate with control)) and source and drain and parallel) and (memory).ab.) and (isolation adj region)) and ((active or diffused) with isolation)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/04 14:02
S14	18	("3660819"   "3728695"   "3744036"   "3755721"   "4203158"   "5260593"   "5293512"   "5511020"   "5616942"   "5650649"   "5766997"   "5864157"   "5901084"   "6008112"   "6060360"   "6060741"   "6097070"   "6201275").PN.	USPAT	OR	ON	2003/04/04 14:05
S15	7	("5138575"   "5349221"   "5408429"   "5589700"   "5627779"   "5850091"   "5854766").PN.	USPAT	OR	ON	2003/04/04 15:03
S16	2	("5850091").PN.	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/04/07 07:33

S17	2	("6240021").PN.	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/04/07 07:37
S18	2	("6060741").PN.	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2003/04/07 07:37
S19	8	(US-6355526-\$ or US-6240021-\$ or US-5796140-\$ or US-5554867-\$ or US-6201275-\$ or US-6060741-\$ or US-5293512-\$ or US-5850091-\$).did.	USPAT	OR	OFF	2003/04/07 08:14
S20	1	((US-6355526-\$ or US-6240021-\$ or US-5796140-\$ or US-5554867-\$ or US-6201275-\$ or US-6060741-\$ or US-5293512-\$ or US-5850091-\$).did.) and copper	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2003/04/07 08:15
S21	16	("5293512" "5295105" "5736442" "58 50091" "6060741" "6201275" "624002 1" "6355526").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 10:19
S22	424	(nonvolatile with memory) and (floating adj gate) and (control adj gate) and (source with metal) and (drain with metal)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 10:47
S23	23	S22 and parallel and orthogonal	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 10:48
S24	193	S22 and (drain with above)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 10:48
S25	682	(nonvolatile with memory) and (floating adj gate) and (control adj gate) and (source with metal) and (drain with metal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 10:47
S26	23	S25 and parallel and orthogonal	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 10:48
S27	11	S26 and (drain with above)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 11:05

S28	193	S25 and (drain with above)	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 11:11
S29	92	S28 and (metal with (conductor or line) with (source and drain))	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 11:37
S30	4	S29 and metal.ti.	USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/26 11:37
S31	3	("5023681"   "5889302"   "5994733"). PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/09/26 11:38
S32	2	("6307229").URPN.	USPAT	OR	ON	2005/09/26 11:39